

PRODUCT BULLETIN # 20674

Generic Copy

Issue Date: 29-Oct-2014

TITLE: NCV4949A (NCV4949A/D) datasheet update

PROPOSED FIRST SHIP DATE: 29-Oct-2014

AFFECTED CHANGE CATEGORY(S): Datasheet

FOR ANY QUESTIONS CONCERNING THIS NOTIFICATION:

Contact your local ON Semiconductor sales office or <Peter.Lanyon@onsemi.com>

NOTIFICATION TYPE:

ON Semiconductor considers this change approved unless specific conditions of acceptance are provided in writing. To do so, contact <quality@onsemi.com>.

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DESCRIPTION AND PURPOSE:

- Change made on page 1 in Features of the datasheet of NCV4949A/D.
 "NCV Prefix for Automotive and Other Applications Requiring Site and Change Control" replaced with "AEC-Q100 Grade 1 Qualified and PPAP Capable".
- 2) Changes made on page 2 in **ABSOLUTE MAXIMUM RATINGS** table of the datasheet of NCV4949A/D. See below highlighted in yellow the updated values.

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
DC Operating Supply Voltage (Note 1)	Vcc	28	٧
Transient Supply Voltage (t < 1.0 s)	V _{CC TR}	40	٧
Output Current	lout	Internally Limited	-
Output Voltage (Note 1)	Vout	20	V
Sense Input Current	Isi	±1.0	mA
Sense Input Voltage (Note 1)	V _{SI}	V _{cc}	-
Output Voltages (Note 1)		A	V
Reset Output	V _{Reset}	20	
Sense Output	V _{SO}	20	
Output Currents			mA
Reset Output	IReset	5.0	
Sense Output	Iso	5.0	
Preregulator Output Voltage (Note 1)	V ₂	7.0	V
Preregulator Output Current	lz	5.0	mA
Reset Delay Voltage (Note 1)	C _T	7.0	V
Reset Delay Current	C-f	Internally Limited	-
ESD Protection at any pin			V
Human Body Model	1	4000	
Machine Model		200	
Charged Device Model (SOIC-20 W)		1000	
Thermal Resistance, Junction-to-Air	Reua		°C/W
SOIC-8		189.3	
SOIC-8 EP SOIC-20 W		84.8 95.8	
Operating Junction Temperature Range	T _A	-40 to +150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device, if any of these limits are exceeded, device functionality hould not be assumed, damage may occur and reliability may be affected.

 Change made on page 3. Note added to ELECTRICAL CHARACTERISTICS / PREREGULATOR table of the datasheet of NCV4949A/D.

ELECTRICAL CHARACTERISTICS (continued) ($V_{OC} = 14 \text{ V}, -40 ^{\circ}\text{C} < T_A < 125 ^{\circ}\text{C}$, unless otherwise specified.) PREREGULATOR

Preregulator Output Voltage (I _Z = 10 µA)	Vz	-	6.3	-	V
Product parametric performance is indicated in the Electrical Characteristics for t					

 Change made on page 4 in PIN FUNCTION DESCRIPTION table of the datasheet of NCV4949A/D. Comment added to Si pin description.

Pin SO-8, SO-8 EP	Pin SO-20 W	Symbol	Description
1	19	Vcc	Supply Voltage
2	20	SI	Input of Sense Comparator. If not used, connect to Vout.
3	1	VZ	Output of Preregulator

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List of affected General Parts:

NCV4949ADR2G NCV4949APDR2G NCV4949ADWR2G

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